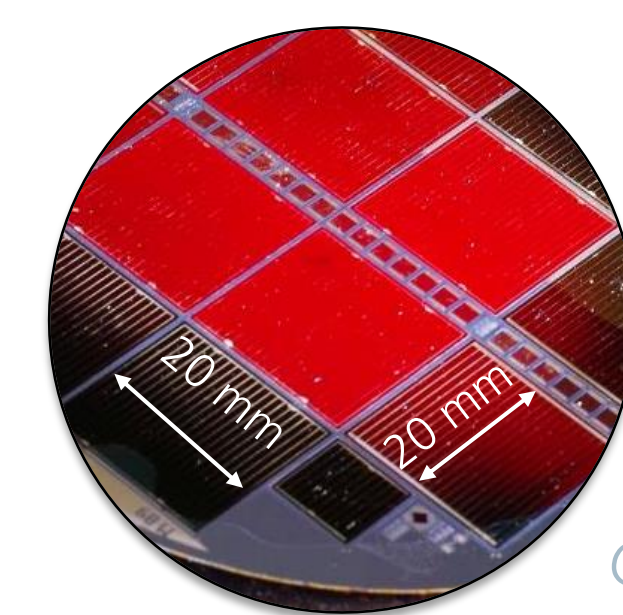
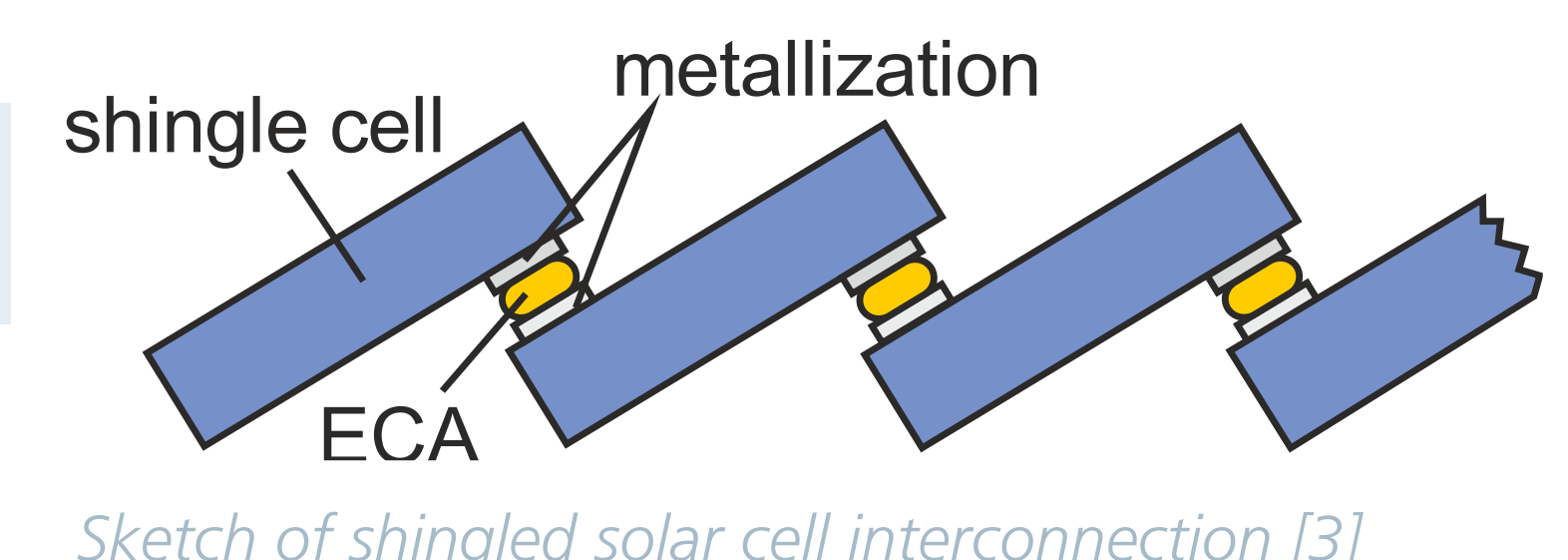


How to Interconnect III-V/Si Tandem Solar Cells for Maximum Module Efficiency

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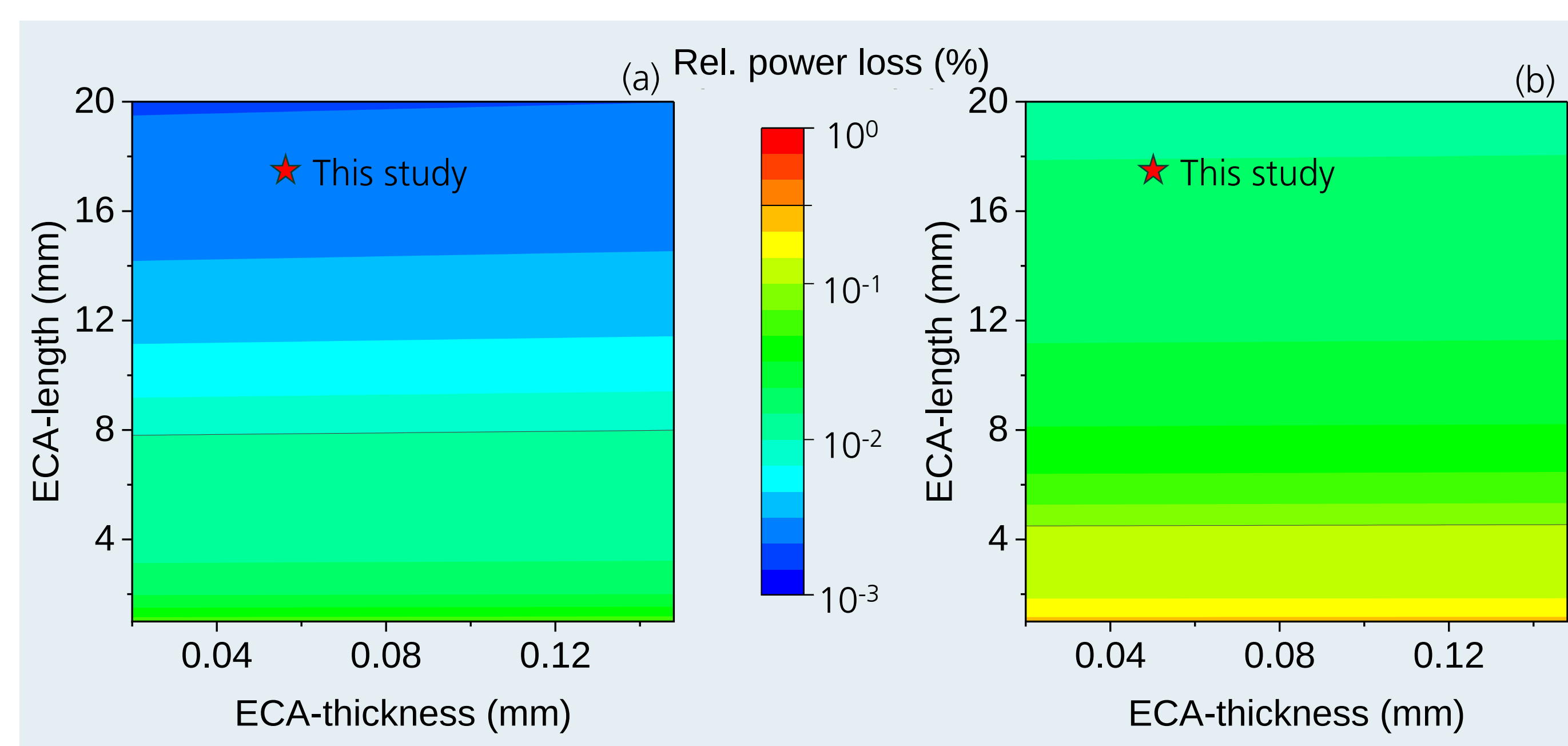
Motivation

- III-V/Si-based tandem solar cells enable maximum efficiencies of currently up to 36.1%[1], while potentially offering higher long-term stability compared to perovskite-Si-based tandem solar cells
 - Shingling allows omitting cell gaps and shading losses due to ribbons/wires and thus, maximizing the active area [2]
- Low cell-to-module losses for III-V/Si solar cells can be realized using the shingling approach



Analytical calculation of cell to string losses

- Contact and volume resistance of the used ECA was measured on a stacked Greek cross like configuration according to [4]
 - $\rho_{\text{contact}} = 0.24 \pm 0.16 \text{ m}\Omega \cdot \text{cm}^2$
 - $\rho_{\text{volume}} = 0.49 \pm 0.21 \Omega \cdot \text{cm}$
- Assumptions
 - 0.3 mm wide ECA line
 - $I_{\text{sc}} = 47 \text{ mA}$
- High measurement error → Evaluation of best- and worst-case scenario
- Interconnection resistance calculation: $R_{\text{int}} = \frac{\rho_{\text{volume}} \cdot t_{\text{ECA}}}{A_{\text{contact}}} + 2 \cdot \frac{\rho_{\text{contact}}}{A_{\text{contact}}}$ [5]
- Power loss estimation: $P_{\text{loss}} = n_{\text{strings}} \cdot n_{\text{joints per string}} \cdot R_{\text{int}} \cdot I_{\text{string}}^2$



Relative module power losses due to interconnection. (a): worst case, (b): best case

Results

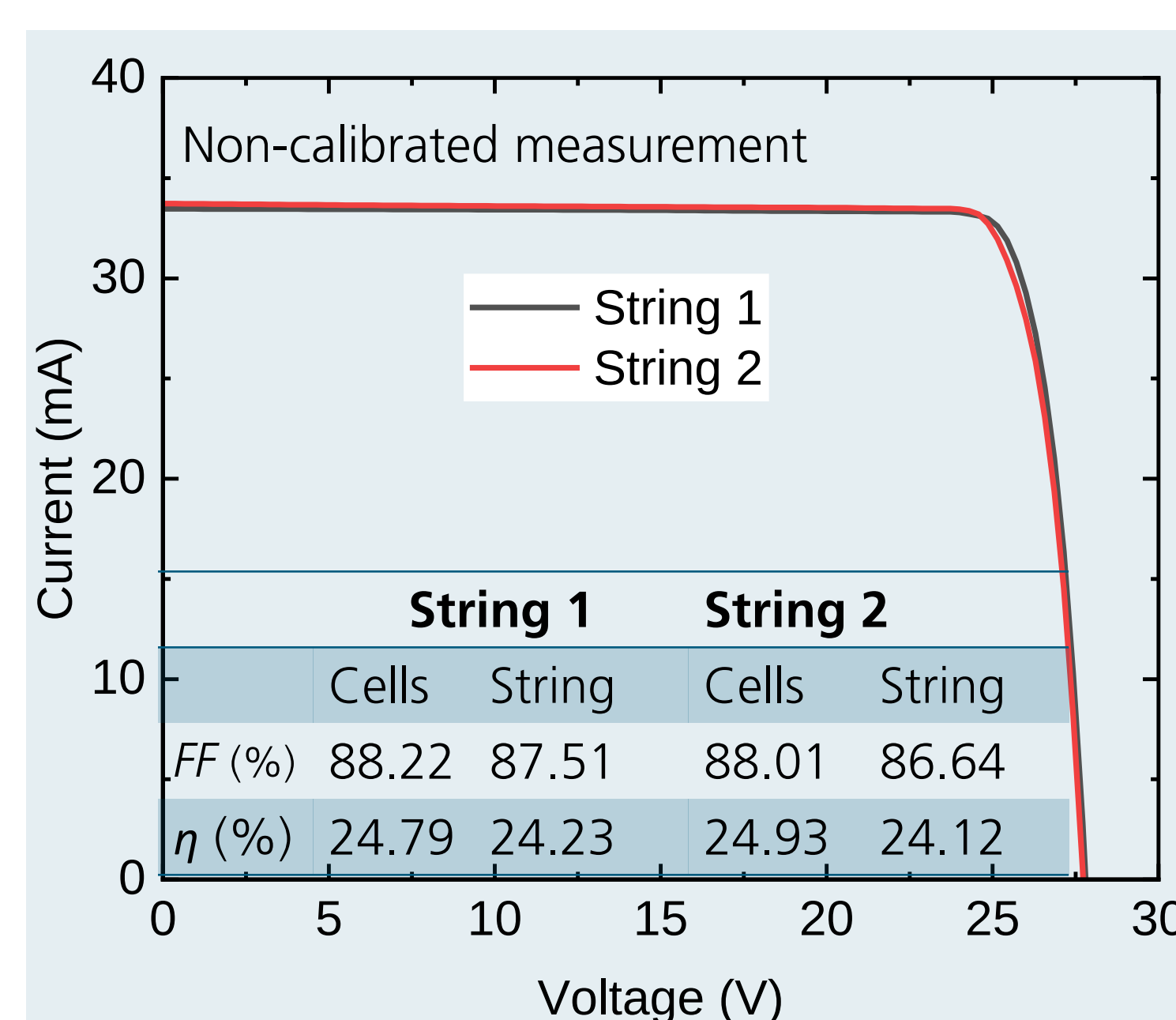
- Interconnection losses are almost independent from the ECA thickness due to low volume resistivity
- Worst case scenario: min. 8 mm ECA length required for $P_{\text{loss, rel.}} < 0.01\%$

Contact

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String and module validation

- Two 9-cell strings produced using a prototype shingle stringer from M10
- Aim: Determination of interconnection losses through IV characterization
- String IV measurements compared to expected values based on cell data



IV characterization of two III-V/Si shingle strings

Results

- $\Delta FF < 1.5\%_{\text{abs}}$: No significant R_{int}
- String 2: Local shunt due to contacting



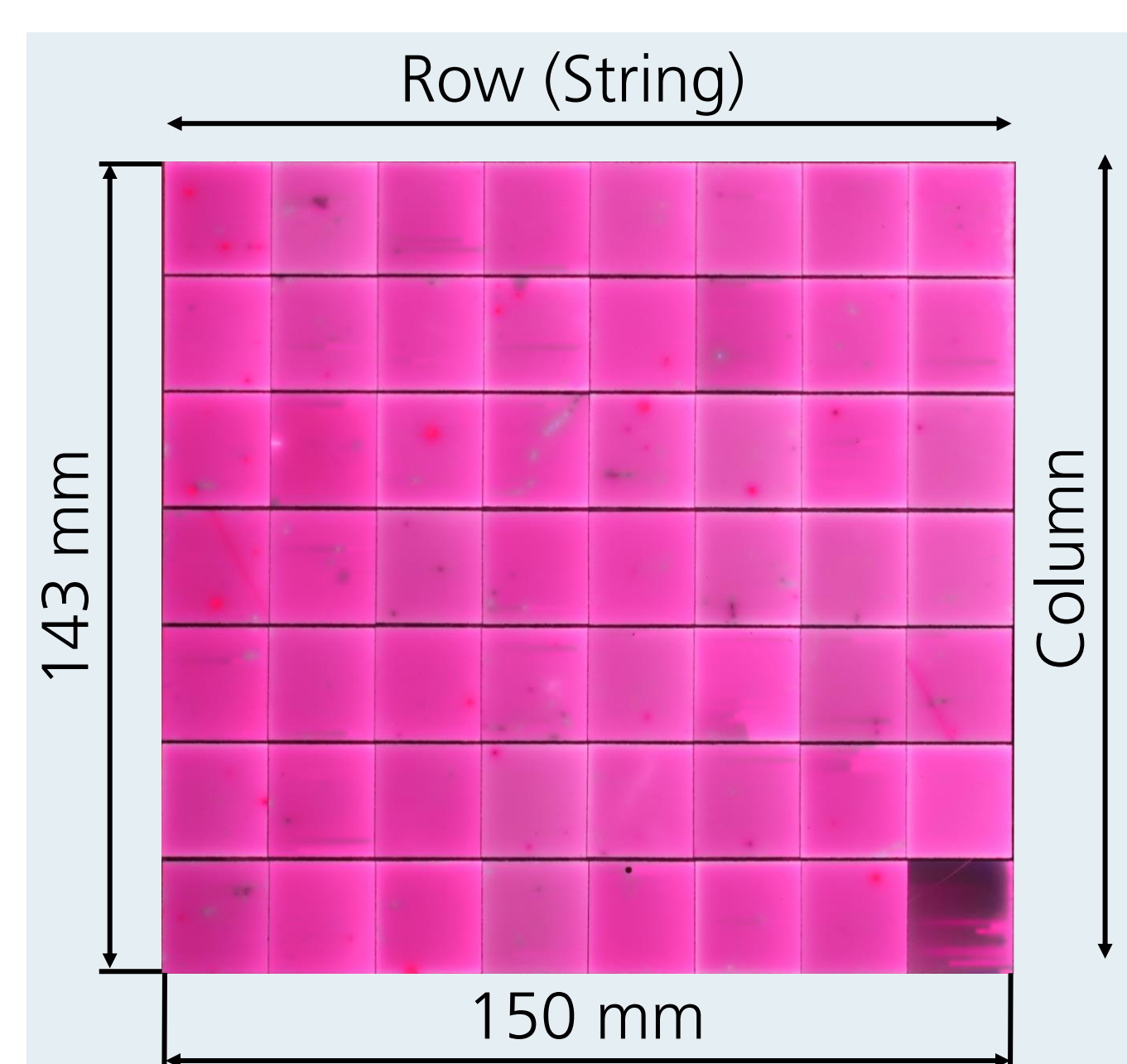
Top cell EL: String 1 @ I_{sc} (35 mA)



Top cell EL: String 2 @ I_{sc} (35 mA)

Module production and characterization

- Production in glass/backsheet configuration on an industrial laminator (Bürkle)
- Active module area: 214.36 cm²



Top cell module electroluminescence image at I_{sc} (320 mA)

Demonstrator module

- Cell efficiency $\eta_{\text{cell}} = (31.86 \pm 0.20)\%$
- ECA length: 18 mm
- String gap: 0.5 mm
- Parallel interconnection in each column

Next steps

- Calibrated IV characterization

Summary

- ECA characterization enables power loss prediction $< 0.01\%$ with optimized interconnection geometry
- 9-cell strings show $\Delta FF < 1.5\%$, confirming minimal interconnection losses
- 7x8 shingle module with 214 cm² module area successfully demonstrated